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November 2013

FQL40N50F

N-Channel QFET® FRFET® MOSFET 500 V, 40 A, 110 mΩ

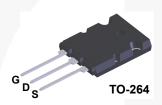
Description

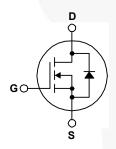
This N-Channel enhancement mode power MOSFET is • 40 A, 500 V, $R_{DS(on)}$ = 110 m Ω (Max.) @ V_{GS} = 10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state • Low Gate Charge (Typ. 155 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 95 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

Features

- $I_D = 20 A$

- · Fast Recovery Body Diode (Max. 250 ns)





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQL40N50F	Unit
V_{DSS}	Drain-Source Voltage		500	V
I _D	Drain Current - Continuous (T _C = 25°C)		40	Α
	- Continuous (T _C = 100°C)		25	Α
I _{DM}	Drain Current - Pulsed	(Note 1)	160	Α
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	1800	mJ
I _{AR}	Avalanche Current	(Note 1)	40	Α
E _{AR}	Repetitive Avalanche Energy	(Note 1)	46	mJ
dv/dt	Peak Diode Recovery dv/dt (No		20	V/ns
P_D	Power Dissipation (T _C = 25°C)		460	W
	- Derate above 25°C		3.7	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T _L	. Maximum lead temperature for soldering, 1/8" from case for 5 seconds.		300	°C

Thermal Characteristics

Symbol	Parameter	FQL40N50F	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.27	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	30	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQL40N50F	FQL40N50F	TO-264	Tube	N/A	N/A	25 units

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Uni
Off Cha	racteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	500			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 250 μA, Referenced to 25°C		0.48		V/°(
I _{DSS}	Zana Oata Waltana Basia Oussant	V _{DS} = 500 V, V _{GS} = 0 V			50	μΑ
	Zero Gate Voltage Drain Current	V _{DS} = 400 V, T _C = 125°C			500	μА
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
On Cha	vo eteriotico					
V _{GS(th)}	racteristics Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 250 μA	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	$V_{GS} = V_{GS}, I_D = 20 \text{ A}$		0.085	0.11	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 50 V, I _D = 20 A		29		S
Dynam C _{iss}	ic Characteristics Input Capacitance	1		5800	7500	pF
Coss	Output Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1.0 MHz		880	1150	рF
C _{rss}	Reverse Transfer Capacitance			95	120	рF
				00	120	Pi
t _{d(on)}	ng Characteristics Turn-On Delay Time			140	290	ns
t _r	Turn-On Rise Time	$V_{DD} = 250 \text{ V}, I_D = 40 \text{ A},$		440	890	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 25 \Omega$		350	700	ns
t _f	Turn-Off Fall Time	(Note 4)		250	500	ns
Q _q	Total Gate Charge	V = 400 V I = 40 A		155	200	nC
Q _{gs}	Gate-Source Charge	$V_{DS} = 400 \text{ V}, I_{D} = 40 \text{ A},$ $V_{GS} = 10 \text{ V}$		37		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		78		nC
	ource Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				40	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				160	Α
V_{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = 40 A			1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 40 A,		>	250	ns
Q _{rr}	Reverse Recovery Charge	dl _F / dt = 100 A/μs		1.3	//	μC

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. L = 2.0 mH, I_{AS} = 40 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C. 3. I_{SD} \leq 40 A, di/dt \leq 200 A/ μ s , V_{DD} \leq BV_{DSS}, starting T_J = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

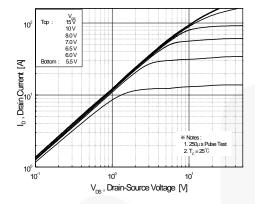


Figure 1. On-Region Characteristics

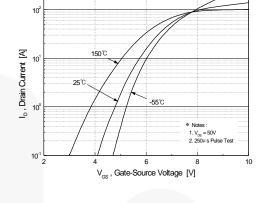


Figure 2. Transfer Characteristics

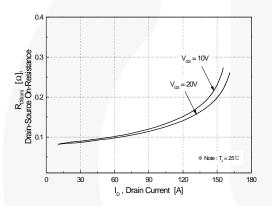


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

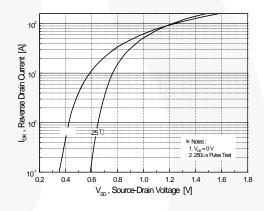


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

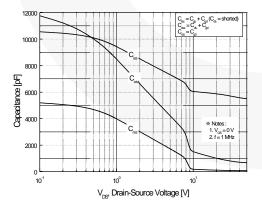


Figure 5. Capacitance Characteristics

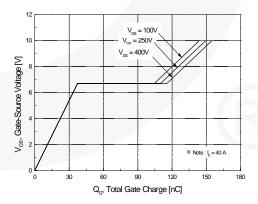
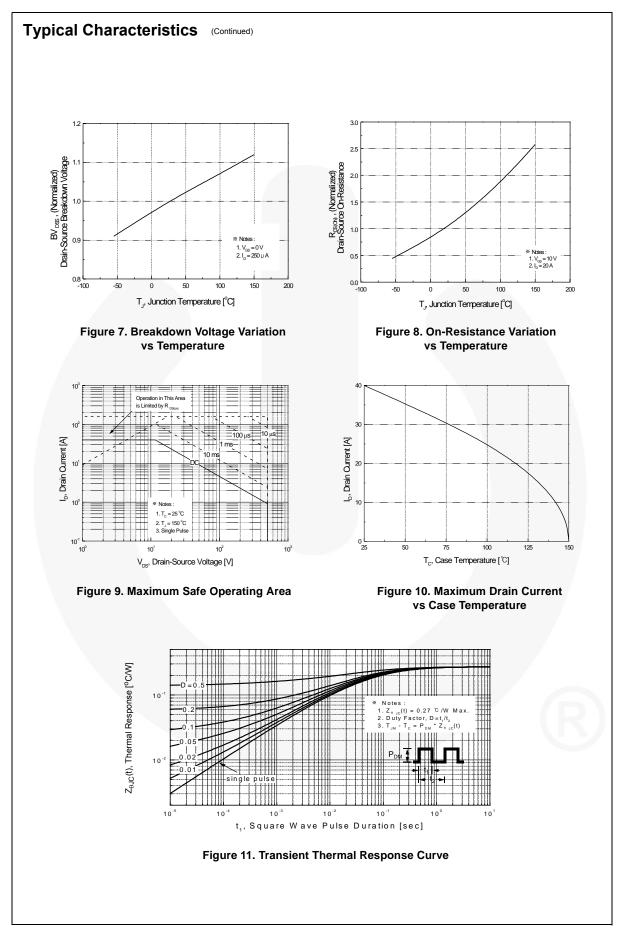


Figure 6. Gate Charge Characteristics



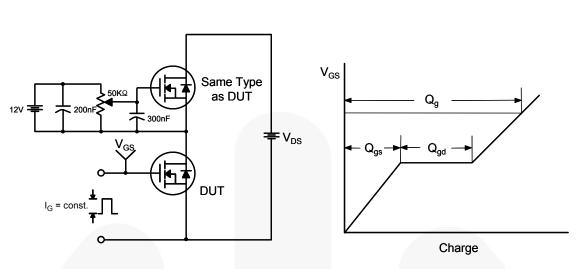


Figure 12. Gate Charge Test Circuit & Waveform

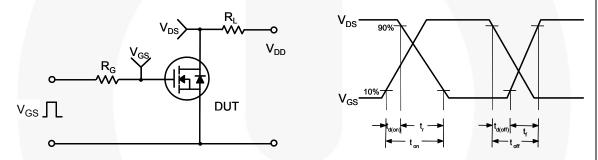


Figure 13. Resistive Switching Test Circuit & Waveforms

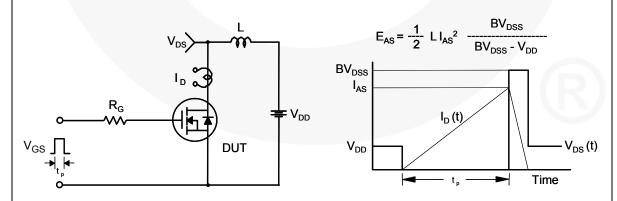
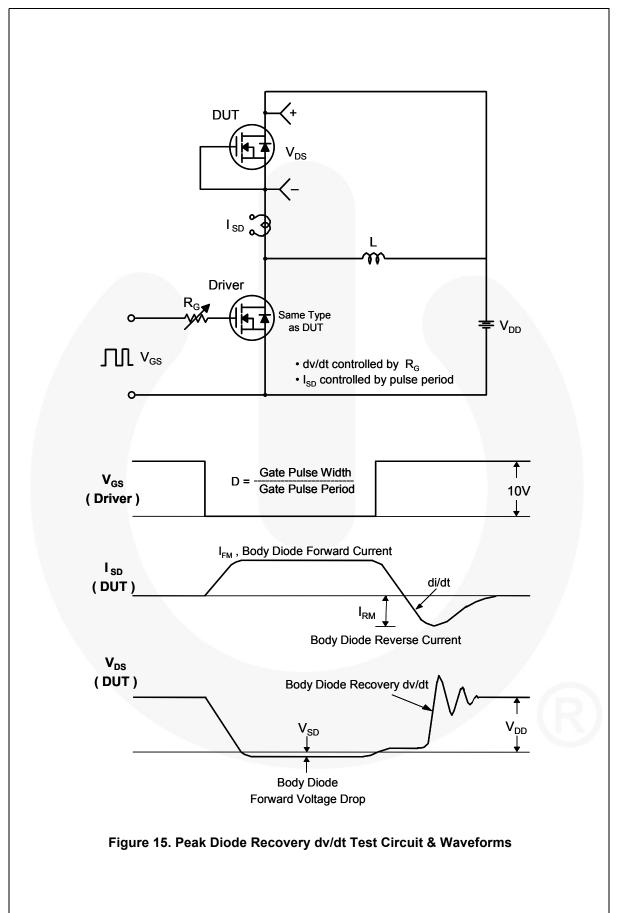
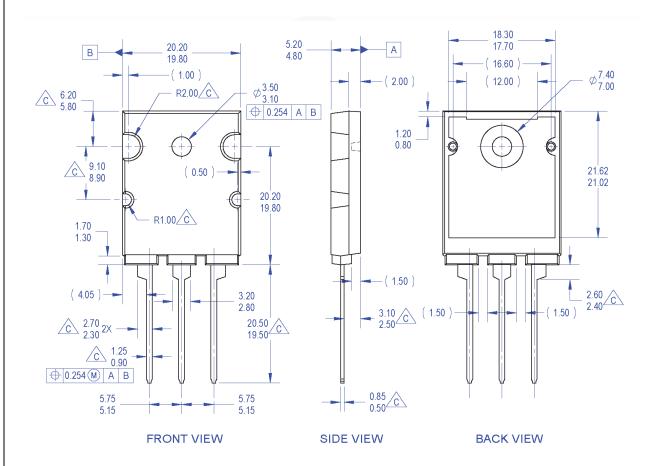
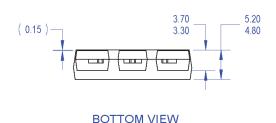


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions





NOTES:

- A. PACKAGE REFERENCE: JEDEC TO264 VARIATION AA
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- OUT OF JEDEC STANDARD VALUE.
 DIMENSION AND TOLERANCE AS PER ASME
 Y14.5-1994.
- E. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS. F. THIS PACKAGE IS INTENDED ONLY FOR "FS PKG CODE AR"
- G. DRAWING FILE NAME: TO264A03REV1

Figure 16. TO264, Molded, 3-Lead, Jedec Variation AA

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